NSN 5962-01-351-7275

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View Online at https://aerobasegroup.com/nsn/5962-01-351-7275

Overall Length:
1.290 inches
Overall Height:
0.425 inches
Body Length:
1.290 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
Between 0.150 inches and 0.210 inches
Maximum Power Dissipation Rating:
320.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
Satellite communications terminal an/usc-3 (v) 1
Features Provided:
Monolithic and static operation and electrostatic sensitive and hermetically sealed and w/disable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Input Circuit Pattern:
21 input
Case Outline Source And Designator:
D-3 mil-m-38510
Current Rating Per Characteristic:
40.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-0.5 volts power source and 8.0 volts power source
Capitance Rating Per Characteristic:

Memory Device Type:

Time Rating Per Chacteristic: 130.00 nanoseconds access

10.00 input picofarads and 7.00 output picofarads

Ram

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96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 printed circuit

2 1 piiillou oilou

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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